TECH PUBLIC
台舟电子

SI3585CDV

N and P-Channel Enhancement Mode Power MOSFET

www.sot23.com.tw

Product Summary

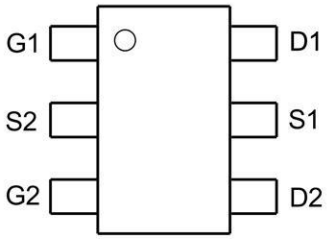
■ 20V, 3.5A, $R_{DS(ON)}$ = 40mΩ @V_{GS} = 4.5V.
$R_{DS(ON)}$ = 50mΩ @V_{GS} = 2.5V.
■ -20V, -2.8A, $R_{DS(ON)}$ = 85mΩ @V_{GS} = -4.5V.
$R_{DS(ON)}$ = 100mΩ @V_{GS} = -2.5V.

Application

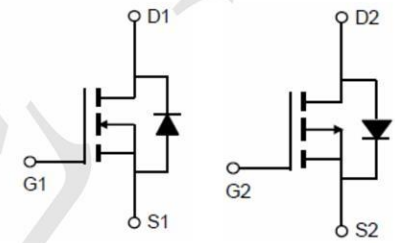
■ DC-DC Converters.
■ Load Switch.
■ Power Management.

Package and Pin Configuration

SOT23-6 Or TSOP-6

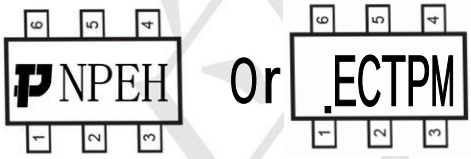


Circuit diagram



N-channel P-channel

Marking:



TPM= TECHPUBLIC MOSFET

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	N-Channel	P-Channel	Units
Drain-Source Voltage	V_{DS}	20	-20	V
Gate-Source Voltage	V_{GS}	±12	±12	V
Drain Current-Continuous	I_D	3.5	-2.8	A
Drain Current-Pulsed [a]	I_{DM}	14	10	A
Maximum Power Dissipation	P_D	1.14		W
Operating and Store Temperature Range	T_J,T_{stg}	-55 to 150		°C

Thermal Characteristic

Parameter	Symbol	Limit	Units
Thermal Resistance, Junction-to-Ambient [b]	$R_{\theta JA}$	110	°C/W

N-CH Electrical Characteristics (T_A=25℃unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} = 0V, I_D = 250μA	20			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 20V, V_{GS} = 0V			1	μA
Gate Body Leakage Current, Forward	I_{GSSF}	V_{GS} = 12V, V_{DS} = 0V			100	nA
Gate Body Leakage Current, Reverse	I_{GSSR}	V_{GS} = -12V, V_{DS} = 0V			-100	nA
On Characteristics [c]						
Gate Threshold Voltage	$V_{GS(th)}$	V_{GS} = V_{DS}, I_D = 250μA	0.4		1.2	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS} = 4.5V, I_D = 3.5A		40	55	mΩ
		V_{GS} = 2.5V, I_D = 2.0A		50	80	mΩ
Dynamic Characteristics [d]						
Input Capacitance	C_{iss}	V_{DS} = 10V, V_{GS} = 0V, f = 1.0 MHz		380		pF
Output Capacitance	C_{oss}			90		pF
Reverse Transfer Capacitance	C_{rss}			60		pF
Switching Characteristics [d]						
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = 10V, I_D = 3.5A, V_{GS} = 4.5V, R_{GEN} = 6Ω		16		ns
Turn-On Rise Time	t_r			16		ns
Turn-Off Delay Time	$t_{d(off)}$			32		ns
Turn-Off Fall Time	t_f			7		ns
Total Gate Charge	Q_g	V_{DS} = 10V, I_D = 3.5A, V_{GS} = 3.3V		3.6		nC
Gate-Source Charge	Q_{gs}			1.0		nC
Gate-Drain Charge	Q_{gd}			1.2		nC
Drain-Source Diode Characteristics and Maximun Ratings						
Drain-Source Diode Forward Current [b]	I_S				1	A
Drain-Source Diode Forward Voltage [c]	V_{SD}	V_{GS} = 0V, I_S = 1A			1.1	V

P-CH Electrical Characteristics (T_A=25℃unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} = 0V, I_D = -250μA	-20			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = -16V, V_{GS} = 0V			-1	μA
Gate Body Leakage Current, Forward	I_{GSSF}	V_{GS} = 12V, V_{DS} = 0V			100	nA
Gate Body Leakage Current, Reverse	I_{GSSR}	V_{GS} = -12V, V_{DS} = 0V			-100	nA
On Characteristics [c]						
Gate Threshold Voltage	$V_{GS(th)}$	V_{GS} = V_{DS}, I_D = -250μA	-0.4		-1.2	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS} = -4.5V, I_D = -2.5A		85	100	mΩ
		V_{GS} = -2.5V, I_D = -1.5A		100	145	mΩ
Dynamic Characteristics [d]						
Input Capacitance	C_{iss}	V_{DS} = -10V, V_{GS} = 0V, f = 1.0 MHz		375		pF
Output Capacitance	C_{oss}			90		pF
Reverse Transfer Capacitance	C_{rss}			60		pF
Switching Characteristics [d]						
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = -10V, I_D = -2.5A, V_{GS} = -4.5V, R_{GEN} = 3Ω		17		ns
Turn-On Rise Time	t_r			17		ns
Turn-Off Delay Time	$t_{d(off)}$			27		ns
Turn-Off Fall Time	t_f			7		ns
Total Gate Charge	Q_g	V_{DS} = -10V, I_D = -2.0A, V_{GS} = -3.3V		2.9		nC
Gate-Source Charge	Q_{gs}			0.46		nC
Gate-Drain Charge	Q_{gd}			1.19		nC
Drain-Source Diode Characteristics and Maximun Ratings						
Drain-Source Diode Forward Current [b]	I_S				-1	A
Drain-Source Diode Forward Voltage [c]	V_{SD}	V_{GS} = 0V, I_S = -1A			-1.1	V

N- Channel Typical Electrical and Thermal Characteristics

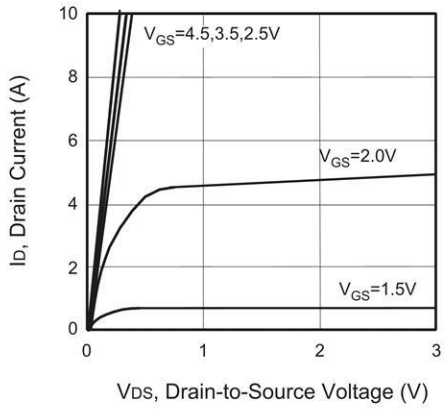


Figure 1. Output Characteristics

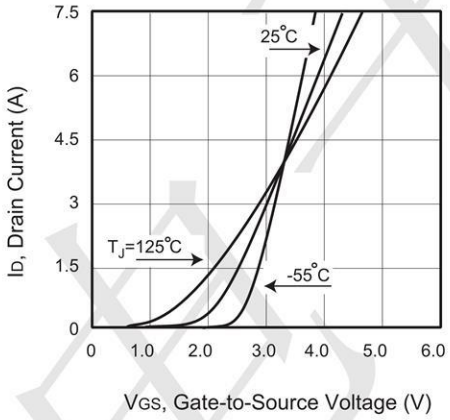


Figure 2. Transfer Characteristics

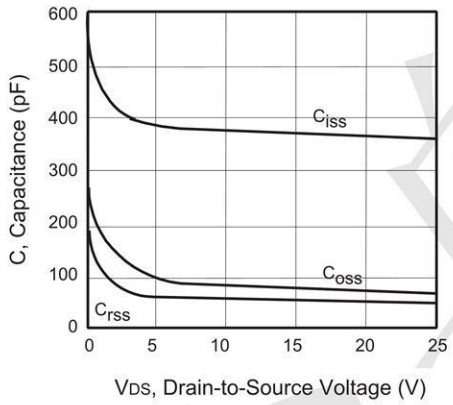


Figure 3. Capacitance

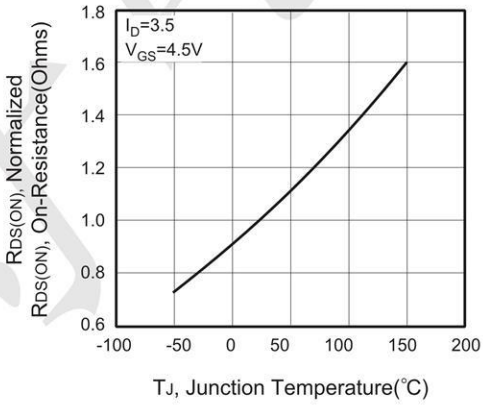


Figure 4. On-Resistance Variation with Temperature

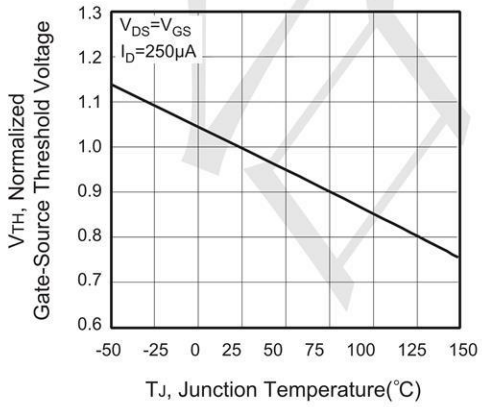


Figure 5. Gate Threshold Variation with Temperature

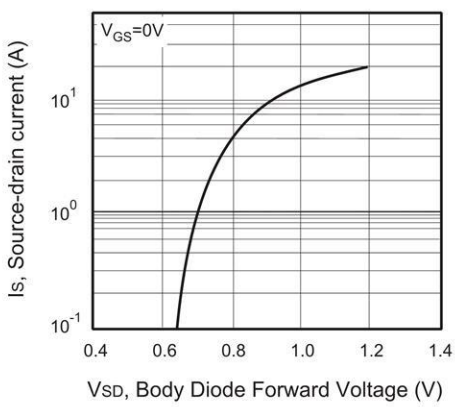


Figure 6. Body Diode Forward Voltage Variation with Source Current

P-CHANNEL

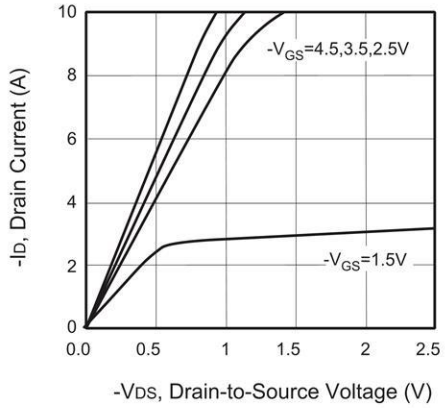


Figure 1. Output Characteristics

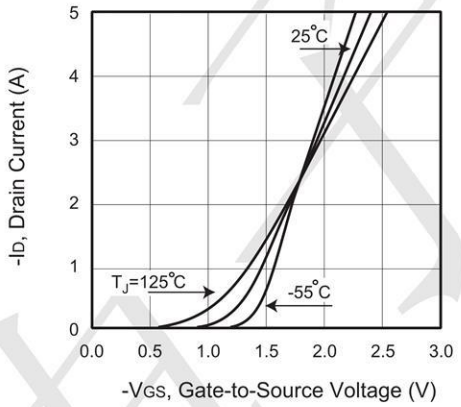


Figure 2. Transfer Characteristics

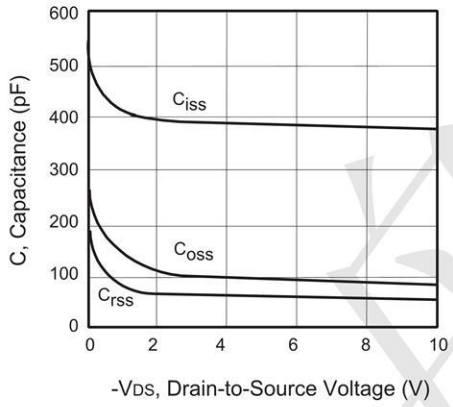


Figure 3. Capacitance

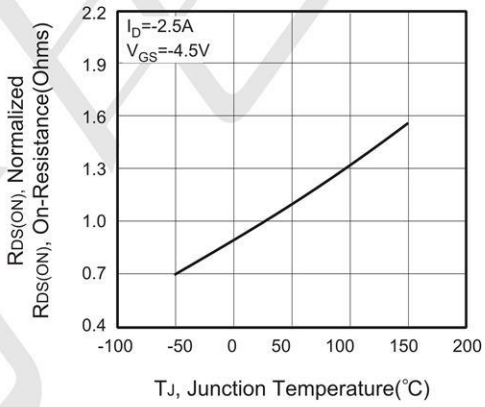


Figure 4. On-Resistance Variation with Temperature

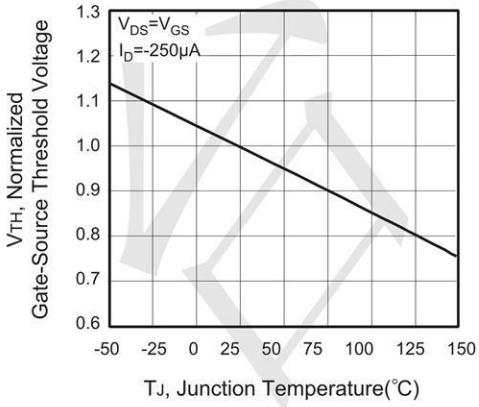


Figure 5. Gate Threshold Variation with Temperature

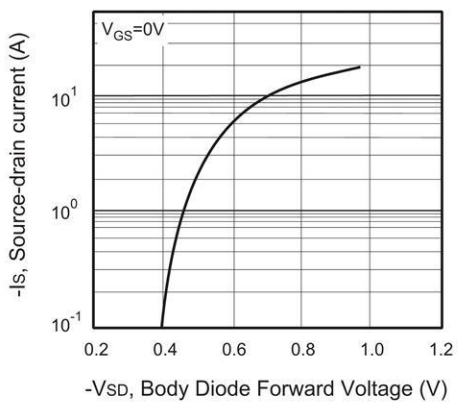


Figure 6. Body Diode Forward Voltage Variation with Source Current

N-CHANNEL

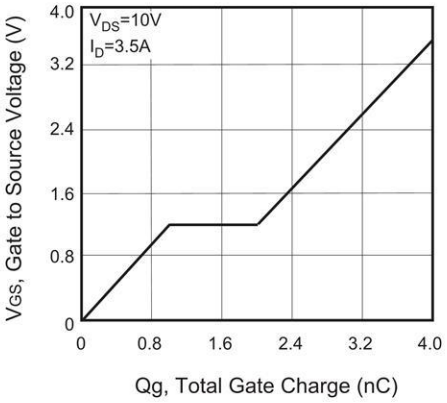


Figure 13. Gate Charge

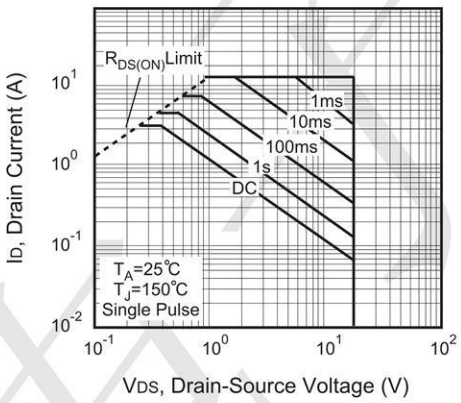


Figure 14. Maximum Safe Operating Area

P-CHANNEL

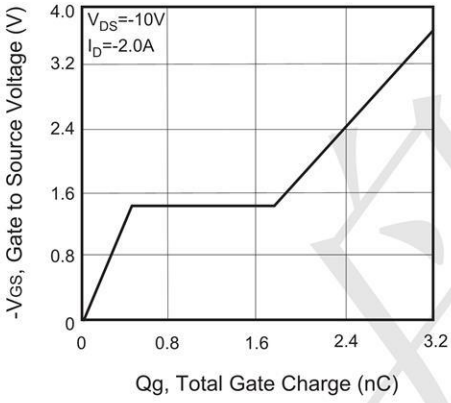


Figure 15. Gate Charge

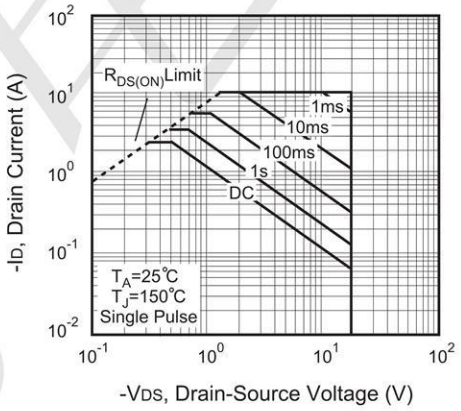


Figure 16. Maximum Safe Operating Area

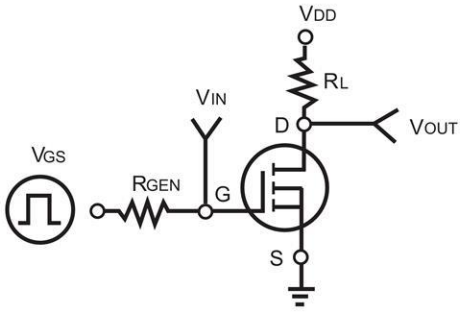


Figure 17. Switching Test Circuit

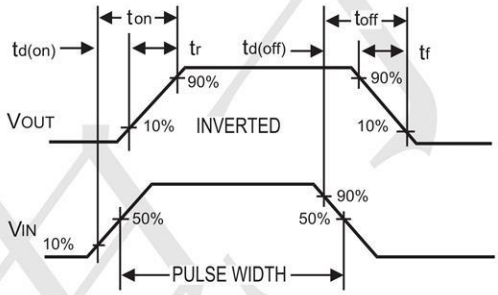


Figure 18. Switching Waveforms

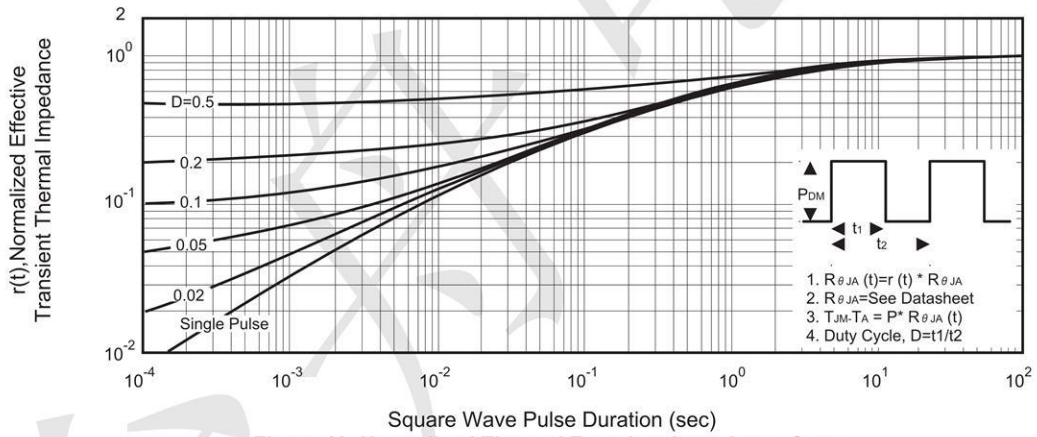
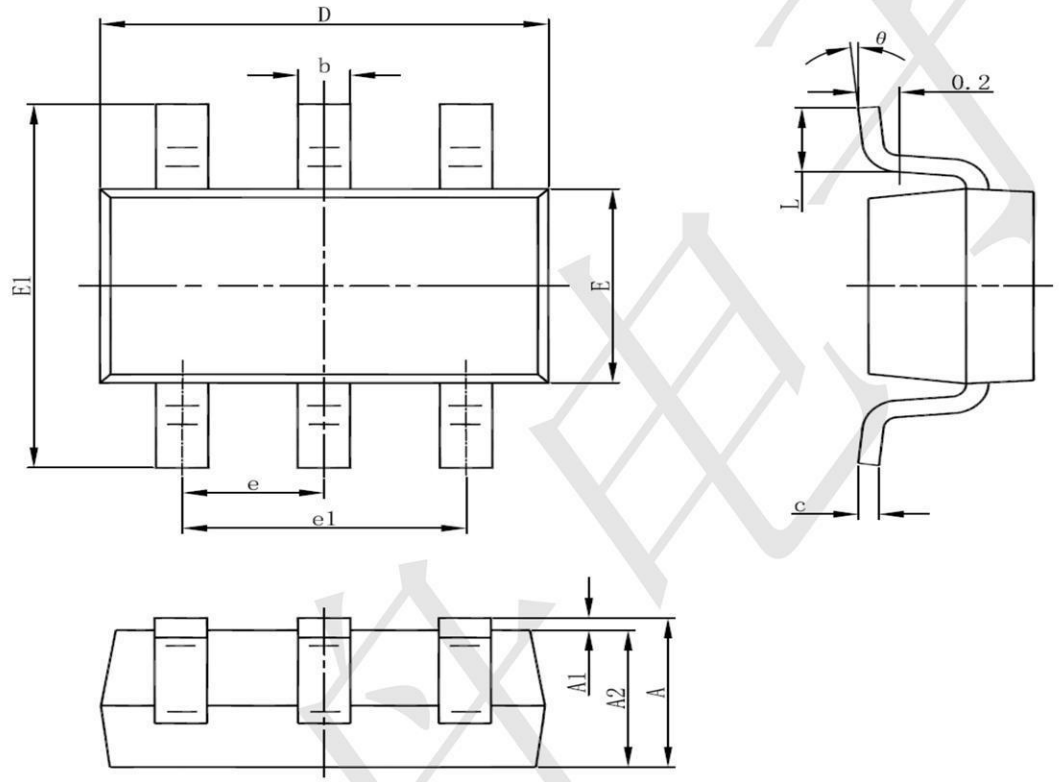


Figure 19. Normalized Thermal Transient Impedance Curve

SOT23-6 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

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